

#### 40V NPN LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

#### **Features**

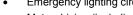
- BV<sub>CEO</sub> > 40V
- I<sub>C</sub> = 5.0A Continuous Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 60mV @ 1A
- $R_{sat}$  = 38m $\Omega$  for a Low Equivalent On-Resistance
- P<sub>D</sub> = 2.4W Power Dissipation
- Complementary part number ZXTP25040DZ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.05 grams (Approximate)

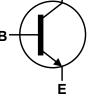
### **Application**

- Emergency lighting circuits
- Motor driving (including DC fans)
- Solenoid, relay and actuator drivers
- DC-DC modules
- **Backlight inverters**
- Power switches
- MOSFET gate drivers

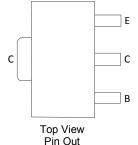


SOT89





Device Symbol



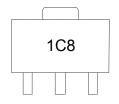
#### Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTN25040DZTA	Standard	1C8	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

### **Marking Information**



1C8 = Product Type Marking Code

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### Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	130	V
Collector-Emitter Voltage (forward blocking)	V <sub>CEX</sub>	130	V
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V
Emitter-collector voltage (reverse blocking)	V <sub>ECO</sub>	6	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	5	Α
Peak Pulse Collector Current	I <sub>CM</sub>	10	Α
Base current	I <sub>B</sub>	1	А

### Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)		1.1		
Linear Derating Factor		8.8		
Power Dissipation (Note 6)		1.8		
Linear Derating Factor	P <sub>D</sub>	14.4	W mW/°C	
Power Dissipation (Note 7)	The PD	2.4		
Linear Derating Factor		19.2		
Power Dissipation (Note 8)		4.46		
Linear Derating Factor		35.7	ı	
Thermal Resistance, Junction to Ambient (Note 5)		117		
Thermal Resistance, Junction to Ambient (Note 6)	Б	63	°C/W	
Thermal Resistance, Junction to Ambient (Note 7)	R <sub>θJA</sub>	51		
Thermal Resistance, Junction to Ambient (Note 8)		28		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

Notes:

<sup>5.</sup> For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.

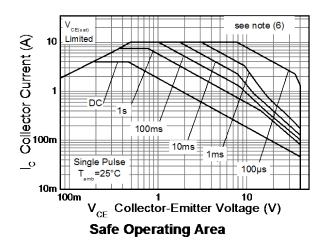
6. Same as note (5), except the device is mounted on 25mm x 25mm x 1.6mm single sided 2oz weight copper.

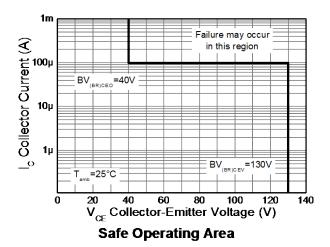
7. Same as note (5), except the device is mounted on 50mm x 50mm x 1.6mm single sided 2oz weight copper.

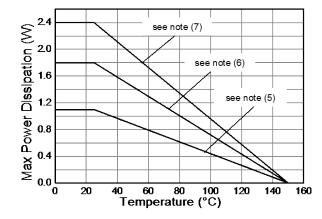
8. Same as note (5), except the device is measured at t<5 seconds.



### **Thermal Characteristics and Derating Information**



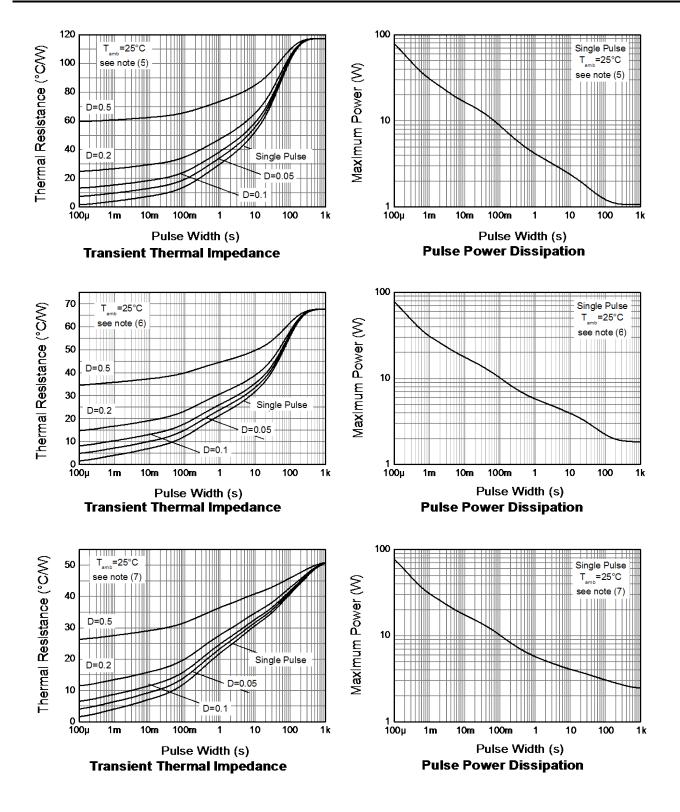




**Derating Curve** 



### **Thermal Characteristics and Derating Information**





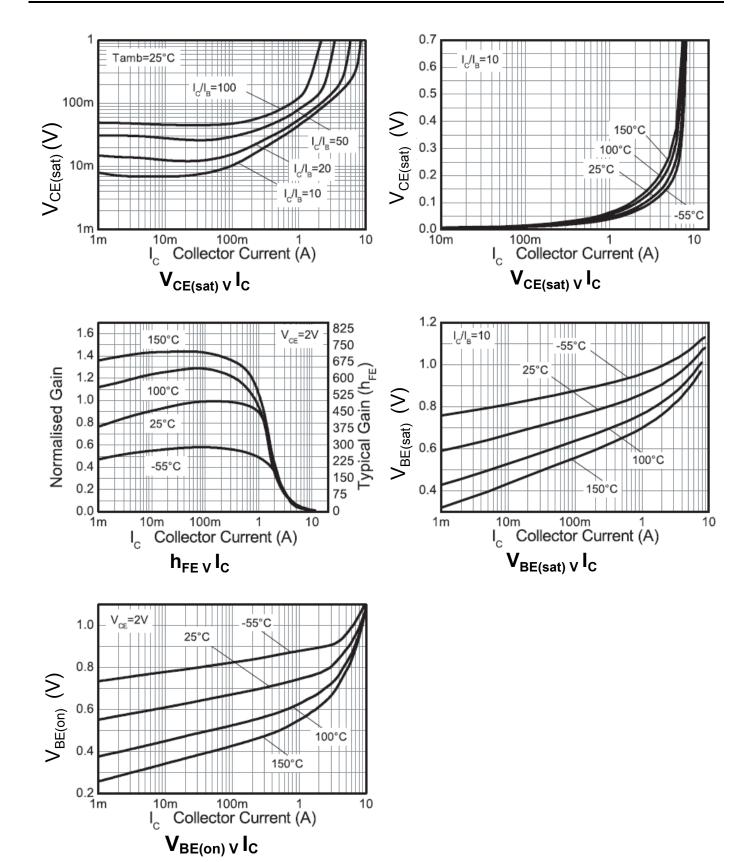
## Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	130	170	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (forward blocking)	$BV_CEX$	130	170	_	V	$I_C$ = 100μA; $R_{BE} \le 1k\Omega$ or -1V < $V_{BE}$ < 0.25V
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	40	63	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.3	_	V	I <sub>E</sub> = 100μA
Emitter-Collector Breakdown voltage (reverse blocking)	BV <sub>ECX</sub>	6	7.4	_	V	$I_E$ = 100μA, $R_{BC} \le 1k\Omega$ or 0.25V > $V_{BC}$ > -0.25V
Emitter-Collector Breakdown voltage	BV <sub>ECO</sub>	6	7.4	_	V	I <sub>E</sub> = 100μA
Collector Base Cut-Off Current	I <sub>CBO</sub>		1 —	50 20	nA μA	V <sub>CB</sub> = 100V V <sub>CB</sub> = 100V, T <sub>A</sub> = +100°C
Collector Emitter Cut-Off Current	l <sub>CEX</sub> R≤1kΩ			100	nA	$V_{CE}$ = 100V; $R_{BE} \le 1kΩ$ or -1V < $V_{BE}$ < 0.25V
Emitter Cut-Off Current	I <sub>EBO</sub>	_	1	50	nA	V <sub>EB</sub> = 5.6V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	50 125 140 190	60 215 215 260	mV	$I_C = 1A$ , $I_B = 100mA$ $I_C = 1A$ , $I_B = 10mA$ $I_C = 2A$ , $I_B = 40mA$ $I_C = 5A$ , $I_B = 500mA$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	_	1000	1100	mV	I <sub>C</sub> = 5A, I <sub>B</sub> = 500mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	_	910	1000	mV	I <sub>C</sub> = 5A, V <sub>CE</sub> = 2V
DC Current Gain (Note 9)	h <sub>FE</sub>	300 300 20 —	450 450 40 10	900 — — —	_	$I_{C} = 10$ mA, $V_{CE} = 2$ V $I_{C} = 1$ A, $V_{CE} = 2$ V $I_{C} = 5$ A, $V_{CE} = 2$ V $I_{C} = 10$ A, $V_{CE} = 2$ V
Transitional frequency	f <sub>T</sub>	_	190	_	MHz	$I_C = 50$ mA, $V_{CE} = 10$ V, $f = 100$ MHz
Output Capacitance	C <sub>obo</sub>	_	11.7	20	pF	V <sub>CB</sub> = 10V, f = 1MHz
Delay time	t <sub>d</sub>		64			101
Rise time	t <sub>r</sub>		108		ne	V <sub>CC</sub> = 10V I <sub>C</sub> = 1A,
Storage time	t <sub>s</sub>		428	] –	ns	$I_C = IA$ , $I_{B1} = -I_{B2} = 10 \text{mA}$
Fall time	t <sub>f</sub>		130			.01 102 1011#1

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



## Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

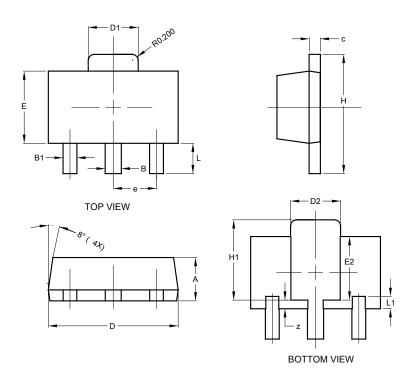




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT89**

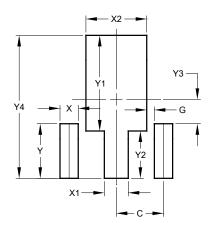


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
C	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	1	-	1.50		
Η	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT89**



Dimensions	Value
Dilliensions	(in mm)
С	1.500
G	0.244
Х	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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